**AMENDMENT TO THE SPECIFICATION** 

Please amend the abstract of the invention as follows:

One embodiment includes non-catalyticlynoncatalytically forming a nanowire on

a substrate from an organometallic vapor without application of any type of reduction

agent. The nanowire is grown during this formation in a direction away from the

substrate and is freestanding during growth. The nanowire has a first dimension of 500

nanometers or less and a second dimension extending from the substrate to a free end of

the nanowire at least 10 times greater than the first dimension. In one form, the

organometallic vapor includes copper and the nanowire essentially consists of elemental

copper, a copper alloy, or oxide of copper. Alternatively or additionally, the nanowire is

of a monocrystalline structure.

Response to Office Action Application No. 10/664,431